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Cite this: DOI: 10.1039/xxxxxxxxxx

Energetics, barriers and vibrational spectra of partially and fully hydrogenated hexagonal boron-nitride

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Received Date
Accepted Date

DOI: 10.1039/xxxxxxxxxx

www.rsc.org/journalname

We study hydrogen chemisorption at full coverage and low concentrations on hexagonal Boron Nitride (h-BN). Chemisorption trends reveal the complex nature of hydrogenation. Barriers for diffusion are found to be significantly altered by the presence of additional H atoms. Moreover, the presence of a Stone-Wales defect may dramatically enhance the bond strength of H to the h-BN surface. These findings provide new insights to understand and characterize hydrogenated Boron Nitride.

1 Introduction

Hexagonal boron nitride (h-BN) is a free-standing two-dimensional membrane closely related to graphene¹. The two materials can be combined to form van der Waals heterostructures², a new class of materials with specific applications to transistors^{3–5}. h-BN forms an ideal substrate for graphene to achieve the highest electron mobility due to its ripple-suppressing surface^{2,6–12}. Graphene and h-BN have many properties in common, e.g., a high mechanical strength, non-solubility in liquid water, and a relatively high room temperature thermal conductivity (0.2 – 0.4 kW/mK for h-BN¹³ compared to ~5 kW/mK reported for graphene¹⁴). However, one key difference is that h-BN is an insulator with a 5.8 eV gap¹⁵ whereas graphene is a semi-metal.

Of the many possible functionalizations of h-BN (see e.g. Ref. 16 for a recent overview), one interesting case is hydrogenation. For graphene this has led to the discovery of graphane¹⁷, which is found to have a reduced lattice constant (2.42 Å) compared to graphene (2.46 Å), and is further characterized by the increased Raman D-peak intensity. Graphane is believed to have a strong tendency to structural disorder due to a low cohesive energy¹⁷. Several works have considered the hydrogenation of monolayer h-BN by atomic hydrogen, both theoretically^{18–26} and experimentally²⁷. Theoretical works considered chemisorption of either one or two H atoms¹⁸, half coverage^{22,25} or full coverage^{19–24,26}. Experiments performed by Zhang et al.²⁷ considered few-layered h-BN on Mo wafers exposed to a H plasma, which was found to lead to a band gap reduction from 5.6 to 4.25 eV in 250 s.

Our motivation is two-fold. First, examine configurations with small number of chemisorbed H atoms which have not yet been considered. Such configurations make a logical intermediate between the chemisorption of a single H atom and a fully hydro-

genated surface. It is moreover not evident that full (crystalline) hydrogenation is kinetically accessible at room temperature. Second, provide an atomistic description of the hydrogenated h-BN surface that may aid in experimental characterization of these surfaces. Here we present the structures of h-BN at increasing hydrogen concentrations and the electronic and vibrational spectra of the lowest energy structures.

2 Methods

Calculations were performed with CP2K²⁸ when using a supercell approach and with Quantum Espresso (QE²⁹) for unit-cell calculations with reciprocal space grids.

For the supercell approach (C2PK), the Quickstep method is employed, with wave functions expanded onto a localized double- ζ -valence-polarized basis set and the electronic density expanded onto a plane-wave basis set with a kinetic energy cutoff of 500 Ry. Goedecker-Teter-Hutter pseudopotentials³⁰ are used to describe the interactions with the core electrons. We use the PBE^{31,32} approximation of the exchange-correlation (xc) functional.

For the unit-cell calculations (QE), we used Martins-Troullier pseudopotentials³³, a 10×10 k-point grid and a plane wave basis set expanded up to 100 (400) Ry for the orbitals (density).

Binding energies are computed as

$$E_b = (E^{h-BN} + n^H E^H - E^{tot})/n^H,$$

with E^{h-BN} and E^H the ground state of pristine h-BN and atomic hydrogen as reference and E^{tot} the total energy of the combined system with h-BN and n^H H atoms. Positive values of E_b imply stable structures with respect to isolated h-BN and atomic H. All total energy comparisons use the same basis set and cell size. Only for the fully hydrogenated h-BN a different cell is considered, as explained later in more detail. Geometries are optimized until the maximum nuclear gradient is smaller than 10^{-4} Ha/bohr.

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3 Structures and Energetics

Table 1 Computed and measured H₂ and h-BN properties

	$E_b^{H_2}/\text{eV}/\text{H}$	$r_{HH}^{\text{H}_2}/\text{\AA}$	$r_{BN}/\text{\AA}$
DFT-PBE	2.30	0.76	1.457
Exp.	2.24 ³⁴ (2.26 at RT)	0.74 ³⁵	1.446 ³⁶ (RT)

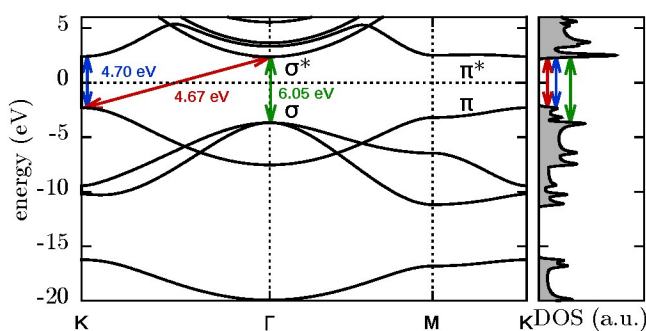


Fig. 1 DFT-PBE electronic band structure of pristine h-BN

We start our investigation by evaluating several basic properties of hydrogen and h-BN. The binding energy and distance of the H₂ molecule are given in table 1. The electronic structure and density of states (DOS) of pristine h-BN are shown in Fig. 1. Experimentally a direct band gap 5.8 eV (215 nm) is observed for h-BN¹⁵ which is underestimated in our DFT-PBE calculations by approximately 1 eV and is moreover found to be almost degenerate with an indirect transition from K to Γ , indicated by the red arrow in Fig. 1. Calculations with the hybrid PBE0 functional (see supplementary information) overestimate the gap with respect to its experimental value by ~ 1 eV.

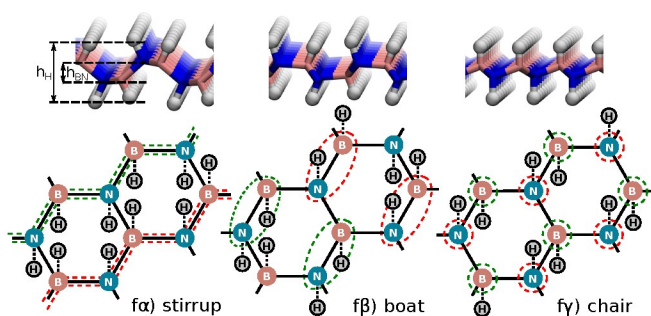


Fig. 2 Side view and schematic illustration of fully hydrogenated h-BN configurations. Red (green) dashed lines indicate B or N atoms with H atoms above (below) the h-BN sheet

Fully hydrogenated h-BN can occur in three non-equivalent ways when considering a double unit cell of h-BN (two B and two N atoms per unit cell) with an equal number of H atoms above and below the layer. These three structures (stirrup, boat and chair or $f\alpha$, $f\beta$ and $f\gamma$ in order of stability) are shown in Fig. 2 and are further characterized in table 2. The stirrup configuration consists of alternating lines of H atoms below and above the membrane which follow the zigzag-lines of h-BN. The boat configuration has alternating pairs of H atoms above/below neigh-

Table 2 Binding energies and bond lengths of the fully hydrogenated structures shown in Fig. 2. Binding energies in brackets refer to the pristine h-BN cell

	$f\alpha$ (stirrup)	$f\beta$ (boat)	$f\gamma$ (chair)
E_b/eV	2.26 (2.14)	2.21 (2.20)	2.18 (2.14)
$r_{BN}/\text{\AA}$	1.59-1.62	1.56-1.60	1.59
$r_{HN}/\text{\AA}$	1.03	1.03	1.04
$r_{HB}/\text{\AA}$	1.23	1.23	1.21
$h_{BN}/\text{\AA}$	1.28	0.81	0.52
$h_H/\text{\AA}$	3.43	3.17	2.77

boring BN pairs, and the chair configuration has alternating H atoms above and below each atom of the pristine lattice.

Full hydrogenation induces a significant pressure, resulting in changes of the equilibrium unit cell. For the chair configuration the unit cell remains hexagonal but the lattice constant expands from 2.50 to 2.58 \AA . For the stirrup and boat configuration, however, the optimized unit cell is monoclinic, with eight atoms (2B, 2N, 4H) per unit cell. The lattice of the stirrup (boat) configuration is defined by $|\vec{a}_1| = 4.64$ (5.06) \AA , $|\vec{a}_2| = 2.60$ (2.59) \AA and $\gamma = 124.1$ (120.7) $^\circ$, compared to the double unit cell of pristine h-BN where $|\vec{a}_1| = 5.00$ \AA , $|\vec{a}_2| = 2.50$ \AA , and $\gamma = 120.0^\circ$. An unambiguous evaluation of these energy differences requires an unchanged basis set. Therefore the number of plane waves is kept fixed between the calculations at different volumes.

For all three full coverage configurations the system becomes more sp^3 -like and strongly non-planar as seen from the values of h_H and h_{BN} in table 2. From table 2, one can also see that the energy gain due to these cell changes for the stirrup, boat and chair configurations are 0.12, 0.01 and 0.04 eV/H respectively. As a consequence, the stirrup becomes the most favourable configuration, whereas for the pristine cell the boat configuration was favoured.

The small energy difference* of 0.05 eV favouring the stirrup ($f\alpha$) over the boat configuration ($f\beta$) agree with previously published results of 0.04^{19,37} and 0.01 eV²⁶. The binding energy difference between the boat and chair configuration ($f\beta$ and $f\gamma$) of 0.07 eV is also in agreement with the 0.03 eV reported previously^{26,37}. Only the 0.27 eV energy difference between $f\beta$ and $f\gamma$, reported by Bhattacharya *et al.*¹⁹, appears to be anomalously large. We note that, contrary to ground state properties, the calculated values of the unoccupied levels are dependent on the basis set and vacuum spacing as discussed in the supplementary information (SI).

We also optimized all possible H chemisorption configurations on a single hexagon in a large supercell (90 B and 90 N atoms in a $21.85 \times 22.71 \times 15.0$ \AA^3 cell with periodic boundary conditions) with at most one H per B/N site. This amounts to 84 configurations in total with n^H between one and six of which 63 were found to correspond to local minima during the optimization. For each n^H , the five most stable configurations are shown in Fig. 3. Note that in 4δ two BN bonds have been broken as can be seen

* Due to differences in reference (E^H) comparing absolute values of E_b is only possible in the case of Tang *et al.*²⁶

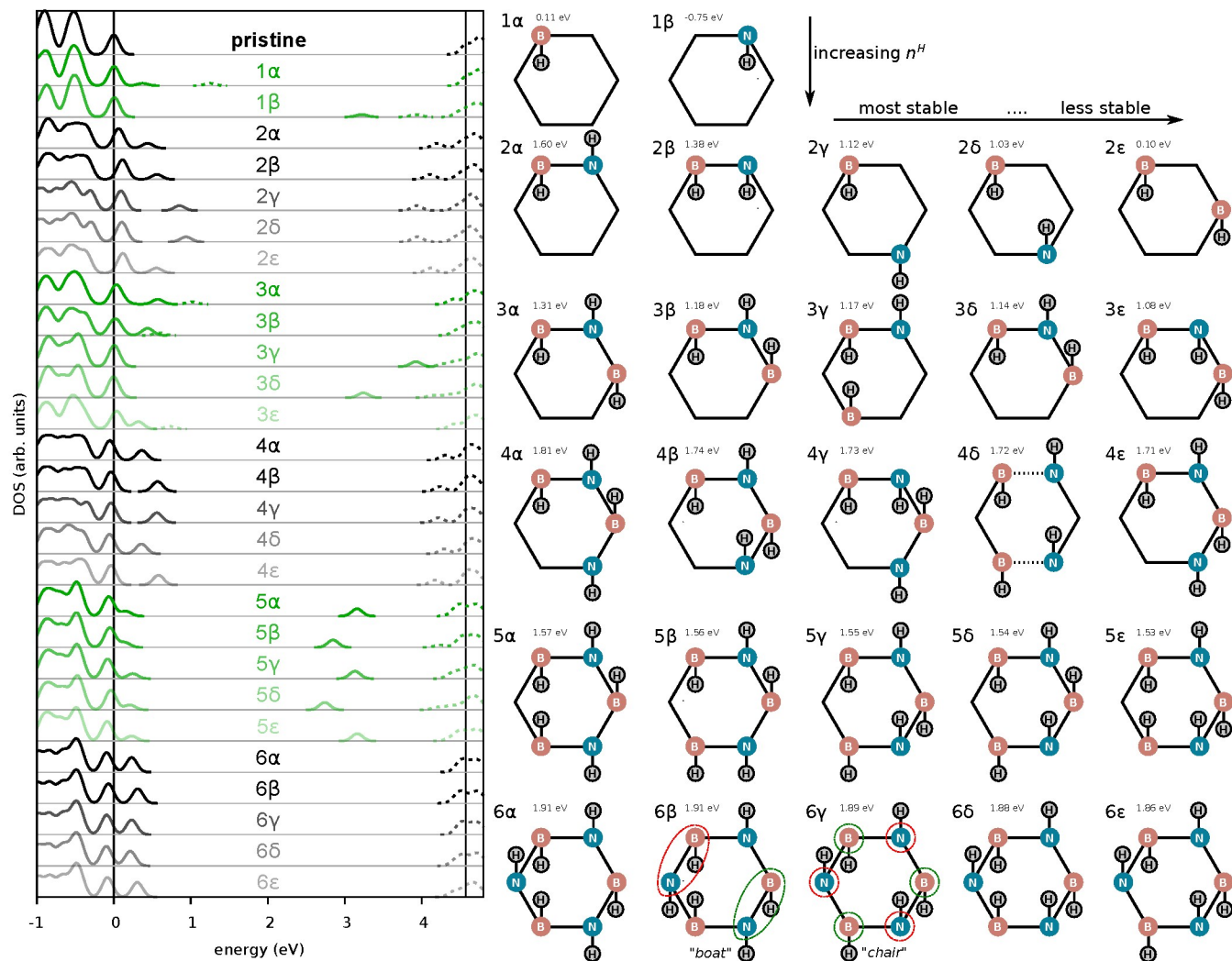


Fig. 3 DOS (left) and schematic illustrations (right) of the 27 (out of 63) most stable chemisorption configurations. In the DOS figures, the unoccupied states are given by dashed lines. Configurations with a spin polarized ground-state (odd n^H) are plotted in green. For each configuration, the binding energy (E_b) is indicated. Dashed lines (4δ) refer to broken BN bonds

more clearly in Fig. S1.

In the left part of Fig. 3 the dependence of the electronic band gap on n^H is shown. For an odd n^H we observe a spin-splitting leading to an occupied/unoccupied state pair in the gap of pristine h-BN. Upon adsorption of an even number of H atoms the system becomes spin-degenerate and (re)opens the gap, although the gap remains smaller than that of pristine h-BN. The most favourable configurations with $n^H = 2, 4$ and 6 are those with the largest electronic gap (for more details see table S4). Considering the most stable configurations for each n^H , the gap initially decreases from the pristine (0H) gap (4.7 eV), and then slowly reopens from 3.8 eV (2H) to 3.9 eV (4H) and finally 4.2 eV (6H).

In Fig. 4 the n^H dependence of E_b and bond distances is shown for all metastable configurations. It can be seen that electron pairing tends to favour configurations with H atoms in proximity rather than at infinite separation. Already for two H atoms the energy gain with respect to 1α is as much as 1.5 eV/H. Moreover, an even number of H atoms is strongly favoured (similarly to the case of BN nanotubes³⁸) with the resulting configurations having

a spin-degenerate ground-state. For three H atoms instead the binding energy is reduced, in contrast to what happens on carbon nanotubes³⁹, where odd numbers of H atoms ($2N+1$) remain comparable in binding energy with the even ($2N$) chemisorbed atoms. As a result it may be preferable for hydrogen to chemisorb in pairs. With an increasing number of H atoms, the number of possible configurations increases rapidly and their binding energies tend to lie close. The binding energy (E_b) finally approaches that of H_2 (2.30 eV) without surpassing it, reaching 1.91 eV for 6H and 2.26 eV for full hydrogenation. This finding implies that hydrogenation requires atomic hydrogen. The BH and NH bond lengths converge rapidly with the number of H atoms (roughly from $n^H = 2$). BN bond distances converge more slowly to their value at full coverage (~ 1.6 Å as seen in table 2) and show a large range of values even for $n^H = 6$. This is because some BN bonds will have two H atoms attached while others have only one, and because the finite number of H atoms creates alternating bond strengths in the BN structure.

We now consider in more detail the individual configurations

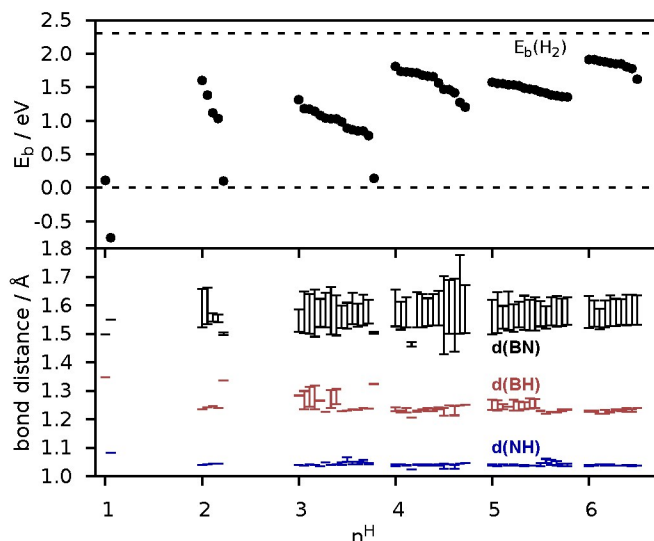


Fig. 4 E_b and bond distance range as a function of the number of H atoms in a hexagon (n^H). $d(\text{BN})$ is the distance from B/N atoms bound to H to any neighbouring B or N atoms. For visualization purposes, points for a given n^H are spread over a larger interval

with the aim of understanding trends in chemisorption.

For a single H atom (1α and 1β of Fig. 3), chemisorption on B or N leads to a locally sp^3 -like geometry. After adsorption the B (N) atom is raised out-of-plane by 0.4 (0.6) Å, with a pyramidalization angle⁴⁰ (Θ_P) of 10° (19°). The BN distances are correspondingly increased from 1.46 Å to 1.50 Å for H chemisorption on B and 1.55 Å on N. Bonding to B occurs with an unusually long BH bond distance of 1.35 Å, while the NH distance is 1.08 Å. Chemisorption on B is associated with a binding energy of $E_b = 0.11$ eV (Refs.^{18,41} report a binding energy of 0.05 and 0.02 eV). Chemisorption on N has $E_b = -0.75$ eV and is thus endothermic.

Two separate effects make H chemisorption on B favoured. First, the geometrical distortion is smaller. The distortion energy — defined as the energy difference of the BN atoms in this configuration compared to the pristine lattice — is 0.47 eV when bonded to B compared to 1.08 eV when bonded to N. Therefore less strain is exerted on the system when H is bonded to B. Second, the ionic nature of BN gives a relative excess charge on B (Mulliken population analysis⁴² gives a net excess charge of $0.35 e^-$ on B), facilitating covalent binding.

Using ab-initio (Born-Oppenheimer) molecular dynamics (MD) in the NVE ensemble we further examined the stability of a single chemisorbed H atom at finite temperatures. Simulations at several relevant temperatures are shown in Fig. 5. These short (1 ps) MD simulations start from the optimized structure with randomized initial velocities. The time-step for the velocity-Verlet integration scheme is 0.5 fs. In these simulations we find that H atoms remain bound to B or to N up to a temperature of ~ 750 K (0.06 eV) or 500 K (0.04 eV) respectively.

The 2α structure (see Fig. 3), a neighbouring BN pair with one H above and one below, appears to be a building block for subsequent low-energy configurations. Different arrangements of it are found in all the most stable structures: $4\alpha, \beta, \delta$ and $6\alpha, \beta, \gamma, \epsilon$

can in principle all be considered as built up by putting together such blocks of neighbouring BN pairs. The small energy differences between different orientations of such blocks (i.e. the small differences between $6\alpha, \beta, \gamma$ and ϵ) moreover indicate a relatively small interaction energy between them. The minimum-energy-state (6α) does not directly correspond to any of the fully hydrogenated structures ($f\alpha, f\beta$ and $f\gamma$) discussed previously and may indicate the onset of more complicated, disordered structures obtained by combining 2α in different ways.

To investigate the effect of the chosen xc functional we repeated the structural optimization of the structures in Fig. 3 with the BLYP^{48,49} functional. We find that BLYP tends to slightly lower the stability of all structures with respect to the PBE binding energies. For $6\alpha - \epsilon$ the BLYP binding energies are 1.86, 1.85, 1.86, 1.83 and 1.81 eV/H compared to 1.91, 1.91, 1.89, 1.88 and 1.86 eV/H found with PBE. For 1α and 1β the effect is slightly larger, with BLYP predicting binding energies of 0.04 and -0.91 eV/H compared to 0.11 and -0.75 eV/H found with PBE.

4 Barriers

Using the climbing-image nudged elastic band (CI-NEB⁵⁰) method we calculated barriers between several thermodynamically relevant structures with CP2K. When a process consists of multiple barriers the calculations is split into multiple CI-NEB calculations to have one climbing image per transition. These barriers are shown in Fig. 6. In the simplest process, $1\beta \rightarrow 1\alpha$, a H atom diffuses between two neighbouring sites by first desorbing from one site and readsorbing on the other. In both cases desorption is associated with a very low energy barrier (0.1 eV from either site, 1α or 1β) and the transition state is characterized as the point where the BH (NH) bond is broken, namely at $r_{BH} = 1.8$ Å or $r_{NH} = 1.3$ Å respectively.

The second process we considered is the permeation of a H atom through the layer, shown in Fig. 6b. In this process H is initially attached to B, and passes and subsequently readsorbs on the same B atom on the other side. This process is associated with a much higher barrier of 2.9 eV. The path for this process passes through the center of a BN bond rather than the center of the hexagon, despite that the latter was used as initial guess for the path. The transition state is characterized by a BH distance of 1.39 Å and a NH distance of 1.05 Å.

When two H atoms are present, a similar process whereby one H passes through the membrane ($2\beta \rightarrow 2\alpha$) is associated with a significantly lower barrier of 1.3 eV as shown in Fig. 6c. Again the transition state is marked by a short NH distance (1.00 Å) when H is in-plane. The BH distance is significantly larger (1.49 Å). Despite reducing the barrier significantly, H atoms caught in a configuration like 2β may thus be expected to remain trapped in this configuration at room temperature.

5 Phonon Spectra and Molecular Vibrations

Phonon spectra and molecular vibrations form an import tool for material characterization. We therefore computed also the phonon dispersions of fully hydrogenated h-BN and the vibrational spectra for configurations with a finite number of H atoms.

The phonon dispersion curves for pristine and fully hydro-

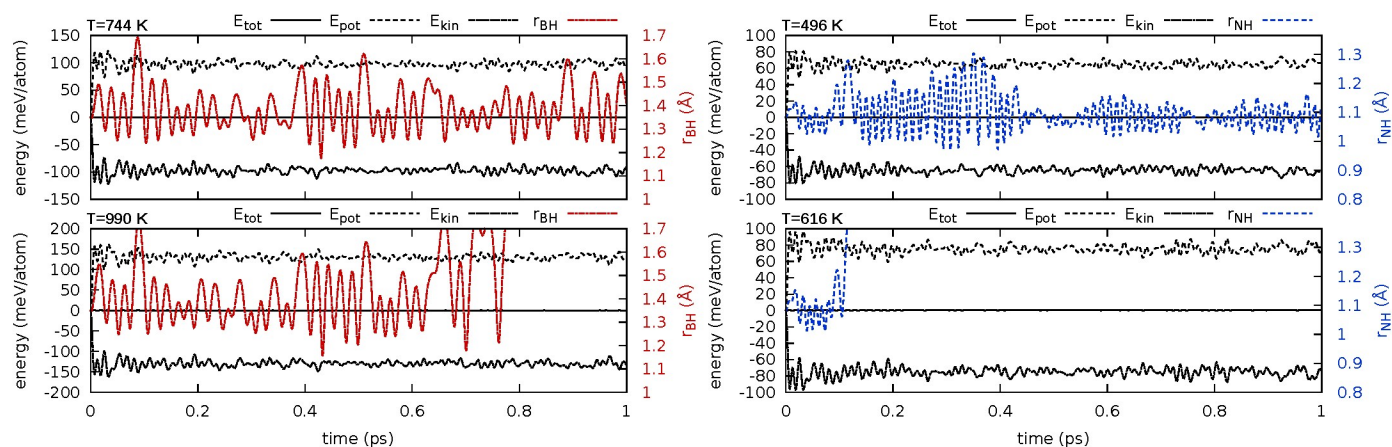


Fig. 5 NVE molecular dynamics of 1α (left) and 1β (right). Black solid, dashed and dash-dotted line represent total, potential and kinetic energy (with $E(t=0) = 0$). The given T is the time-average over the last 0.5 ps. Initial kinetic energies are 1500 and 2000 K for 1α and 1000 and 1200 K for 1β

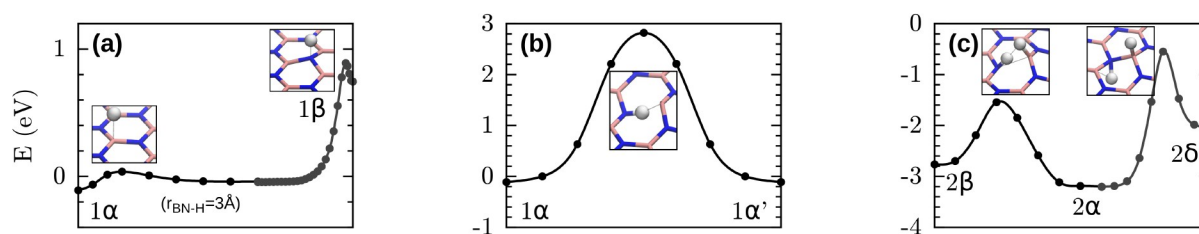


Fig. 6 Barriers: (a) diffusion between 1α and 1β , (b) penetration of h-BN from 1α to $1\alpha'$ on the other side of the membrane, (c) diffusion and penetration of h-BN with a second H present (conversion between 2α and $2\beta/2\gamma$). The energy scale is chosen such that $E = -n^H E_b$.

generated h-BN are shown in Fig. 7. The phonon spectrum of h-BN may be compared to Slotman *et al.*⁵¹, Kern *et al.*⁵² and those of fully hydrogenated h-BN to Thapa and Das⁵³. In particular, the pristine h-BN phonon spectrum shown in Fig. 7a is in excellent agreement with experimental observations. The (Raman active) BN stretching mode is found at 1349 cm^{-1} compared to the 1373 cm^{-1} found experimentally⁵⁴. Good agreement between calculations with two different computational approaches (large cell calculations done with CP2K versus unit cell calculations done with QE) can also be inferred from the DOS plotted on the right for each of the dispersion curves in Fig. 7 (black and blue curves for QE and CP2K respectively). A further comparison between QE and CP2K results in terms of structural properties is given in the supplementary information, table S1.

For the optimized pristine h-BN cell, the out-of-plane acoustic mode (ZA) has the anomalous quadratic dispersion⁵⁵

$$\omega_{ZA}(q) = \sqrt{\frac{\kappa}{\rho}} q^2,$$

where κ is the bending rigidity, $\rho = 2(m_B + m_N)/\sqrt{3}a^2$ is the 2D mass density. Any strain would add a linear term proportional to C_{44} . To illustrate this effect, in Fig. 9 the ZA-mode dispersion in the optimized cell is compared to that obtained in a 0.2% larger cell, where it can be seen that this expansion changes the dispersion from quadratic to linear, forming an independent test for unit cell optimization. For pristine h-BN κ is found to be 1.26 eV. We note that at the non-optimal cell the LO and TO modes are also

modified, being reduced by roughly 10 cm^{-1} for a 0.2% increase in lattice parameter.

Full hydrogenated changes also the BN modes. The BN band edge is reduced by more than 200 cm^{-1} from 1521 cm^{-1} to 1311 cm^{-1} (stirrup), 1303 cm^{-1} (boat) or 1263 cm^{-1} (chair). In particular, the chair configuration (γ) also creates a gap of $\sim 125 \text{ cm}^{-1}$ between the optic and acoustic modes ($678 - 805 \text{ cm}^{-1}$)

We also computed vibrational spectra for structures with a finite number of H atoms. We focus on two main parts of the spectra. The first part is the region around 700 cm^{-1} where the chair configuration opens a gap in the DOS, whereas the pristine and other hydrogenated samples do not. The second part is the region of $2400 - 3200 \text{ cm}^{-1}$ where differences in BH and NH stretching modes frequencies may be most clearly observed.

In Fig. 10 the DOS projected onto the atoms bound to H is shown for several 6H configurations. A reduction in the DOS is observed for all structures considered in the region of $600 - 800 \text{ cm}^{-1}$, as seen for the chair configuration in Fig. 7d. Moreover, configuration 6γ , which can be considered the precursor of the chair structure as indicated by the coloured circles in Fig. 2 and 3 clearly shows the most pronounced reduction in DOS in this region as expected.

The range of frequencies associated with BH and NH stretching modes are summarized in table 3. When only a single H atom is bonded to B, the BH bond is weak, with a bond length as large as 1.35 \AA , resulting in a mode of 1563 cm^{-1} , just above the pris-

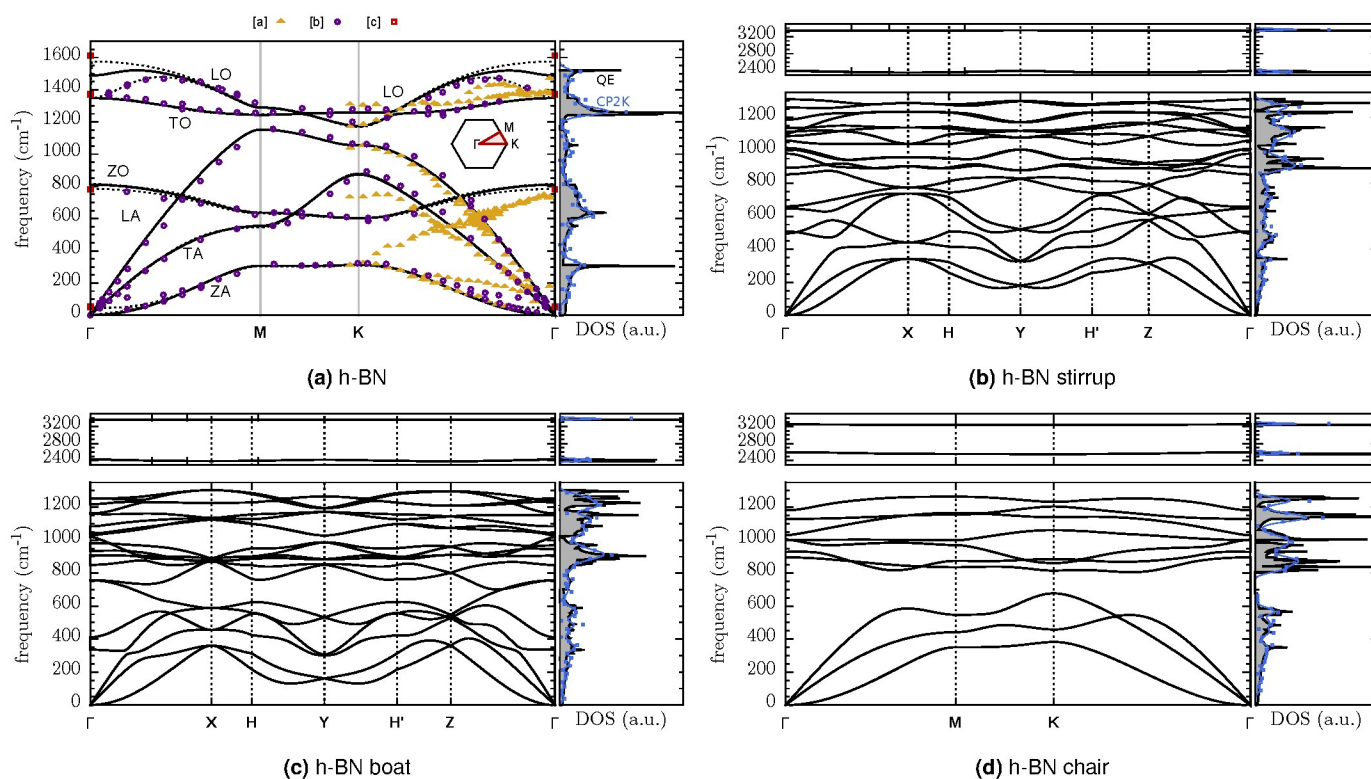


Fig. 7 DFT-PBE phonon dispersion of (a) pristine h-BN, and hydrogenated h-BN in the (b) stirrup, (c) boat and (d) chair configuration. The reciprocal space paths are explained in Fig. 8. [a]=Rokuta *et al.*⁴³ (HREELS), [b]=Serrano *et al.*⁴⁴ (inelastic x-ray scattering) [c]=Geick *et al.*⁴⁵, Nemanich *et al.*⁴⁶, Reich *et al.*⁴⁷ (Raman and IR at Γ). Solid (dashed) lines are for monolayer (bulk). The DOS shown is that of monolayer h-BN. Blue lines and squares give the DOS from supercell calculations (CP2K) as Gaussian broadening (width 25 cm^{-1}) or histogram (25 cm^{-1} intervals) respectively

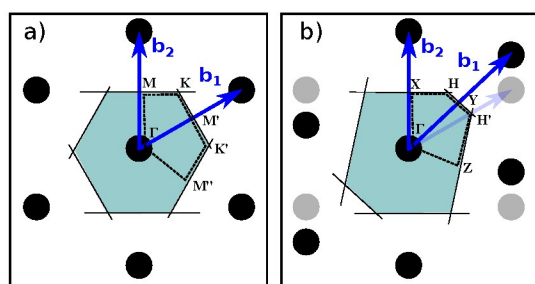


Fig. 8 Construction of the Brillouin Zone and high symmetry points. Pristine h-BN and Γ_2 have a hexagonal unit cell (a), with (in 2D) $\mathbf{b}_1 = (1, 1/\sqrt{3})$ and $\mathbf{b}_2 = (0, 2/\sqrt{3})$ in units of $2\pi/a$. Γ_2 and Γ_3 have a monoclinic cell (b) with $\mathbf{b}_1 = (1, -1/\tan \gamma)$ and $\mathbf{b}_2 = (0, a/b \sin \gamma)$. The constructed path in terms of reciprocal unit vectors (\mathbf{b}_i) is given by $\Gamma = (0, 0)$, $X = (0, 1/2)$, $K = H = (1/3, 1/3)$, $Y = (1/2, 0)$, $H' = (2/3, 1/3)$ and $Z = (1/2, -1/2)$. M and K refer to the hexagonal cell ($\gamma = 120^\circ$, $a = b$)

tine h-BN band edge of 1521 cm^{-1} . With additional H atoms, the bond is strengthened, becoming a full single bond ($r_{BH} = 1.20 \text{ \AA}$) and making the system spin-degenerate. As a result the associated BH frequency approximately doubles. Conversely, when H is bound to N (1β), we directly find a much higher frequency of 2479 cm^{-1} . The range of both the ν_{NH} and ν_{BH} modes depends significantly on the configuration under consideration, with differences of about 200 cm^{-1} for configurations with comparable binding energy. In comparing the fully hydrogenated with par-

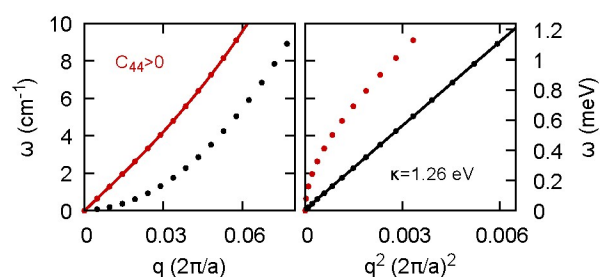


Fig. 9 Dependence of the ZA mode for pristine h-BN near Γ (M direction) on q (left) or q^2 (right). In black, results for the optimized cell showing $\omega \propto q^2$. The red curve shows the $\omega \propto q$ behaviour in a 0.2% larger cell

tially hydrogenated structures (as represented by those with 6H), we see that the width of the BH modes grows from 20 cm^{-1} to 70 cm^{-1} . Therefore, a disordered hydrogenated structure may be expected to display a broader band for the BH modes.

6 Hydrogenation of SW defects

Finally we also considered chemisorption on a Stone-Wales (SW) defect, as shown in Fig. 11 and table 4. The SW defect geometry is shown in the lower panel of Fig. 11 and is found to have a formation energy of 6.9 eV. For comparison, for BN nanoribbons, the SW formation energy was found to increase from 5.9 – 6.3 (this range is due to the orientation on the ribbon) to 6.4 – 6.8 eV

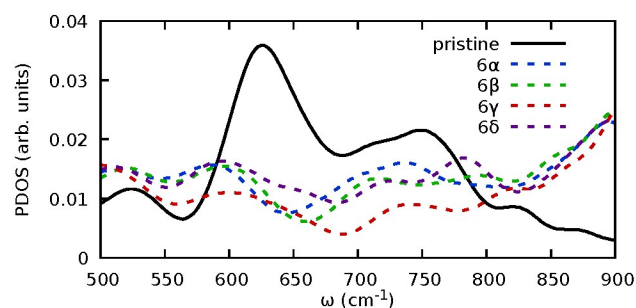


Fig. 10 Vibrational DOS in the range 500 – 900 cm^{-1} . The DOS is projected onto B and N atoms in the hexagon where H is chemisorbed

Table 3 Fundamental frequencies of several configurations in Fig. 3. Range of vibrational frequencies associated with BH / NH stretching modes. Numbers refer to supercell-approach calculations. Numbers in parentheses are computed using the unit cell approach (QE). Differences smaller than 1% between the two computational approaches are attributed to the basis set differences

	ω_{NH} (cm^{-1})	ω_{BH} (cm^{-1})
1α		1563
1β	2479	
2α	2350	3326
2β	2302	3330
2γ	2306	3307
4α	2308, 2406	3315, 3375
4β	2387, 2446	3291, 3306
6α	2370 – 2424	3308 – 3375
6β	2390 – 2417	3308 – 3354
6γ	2458 – 2484	3277 – 3280
6δ	2336 – 2472	3292 – 3342
$f\alpha$	2361 – 2460 (2357 – 2405)	3361 – 3371 (3342 – 3350)
$f\beta$	2392 – 2442 (2391 – 2424)	3374 – 3384 (3355 – 3361)
$f\gamma$	2559 – 2610 (2549 – 2594)	3255 – 3272 (3235 – 3245)

upon increasing the nanoribbon width from 1.4 to 2.6 nm⁵⁶.

In this case there are of course many more possible chemisorption sites even for a single H. The most favourable sites are again those when H is bonded to B with an associated binding energy of 1.66 eV much greater than for pristine h-BN (0.11 eV), however still significantly lower than the H₂ binding energy (2.30 eV).

The chemisorption of a dimer however, attains a binding energy of 3.36 eV/H. In contrast to pristine h-BN, where binding to B was found to be preferable, the most favourable SW:2H configuration is when both H are attached to (neighbouring) N atoms. The binding energy of this configuration (as well as other dimer configurations) thereby surpass even that of molecular hydrogen, similarly to what was found for graphene⁵⁷. Taking into account the defect formation energy however it remains favourable to reconstruct the lattice and have molecular hydrogen separately.

7 Conclusions

Chemisorption of H on h-BN is in many ways similar to that of graphene^{17,58,59}: H atoms prefer chemisorption in pairs on the different sublattices, and full hydrogenation eventually results in a structure only slightly less stable than the pristine lattice with molecular hydrogen. However, for the chemisorption of a single H atom, h-BN is much less reactive than graphene, with a binding energy of 0.1 eV on h-BN versus 1.4 eV on graphene. Moreover,

the structure of fully hydrogenated h-BN is qualitatively different from that of graphene and leads to a monoclinic lattice.

In the experiments where h-BN was exposed to a H plasma²⁷, a band gap reduction of ~ 1.35 eV was observed with only minor deviations in the E_{2g} mode at 1373 cm^{-1} after hydrogenation. Given the results presented here, it seems reasonable to expect that these samples were not fully hydrogenated. The changes in vibrational frequencies and band gap reduction may be more easily explained by small groups of H atoms on the surface, resulting in localized impurity states where the BN spectrum is less affected.

The characterizations of the unit cell and structural changes, as well as of the electronic and vibrational structure that we have provided here may help characterize these structures more carefully. It may therefore be insightful to resolve the detailed structure of h-BN exposed to atomic hydrogen by means of atomic spectroscopy methods and consider elevated temperatures for chemisorption.

The research leading to these results received funding from the Foundation for Fundamental Research on Matter (FOM), part of the Netherlands Organisation for Scientific Research (NWO). The work was carried out on the Dutch national e-infrastructure with the support of SURF Cooperative. A.F. and M.L.K. acknowledge financial support from the European Union Seventh Framework Programme under Grant No. 604391 Graphene Flagship. We thank W. Brandeburgo, E.J. Meijer and R.C. Ouwersloot for useful discussions.

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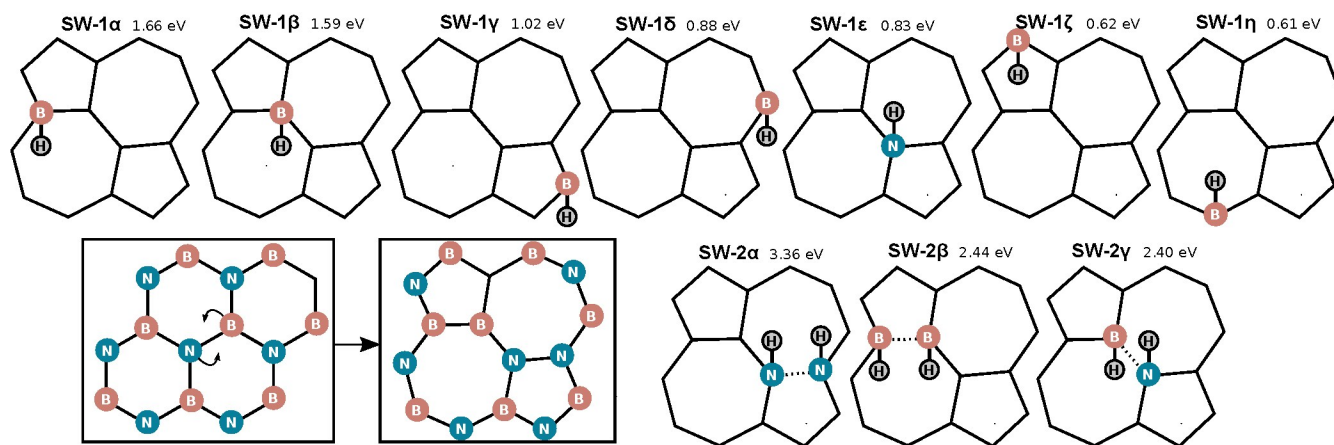


Fig. 11 Hydrogenation of a Stone-Wales defect (N in blue, B in pink and H in white)

Table 4 Energetics (in eV) and bond lengths (in Å) of the structures in Fig. 11

	SW-1 α	SW-1 β	SW-1 γ	SW-1 δ	SW-1 ϵ	SW-1 ζ	SW-1 η	SW-2 α	SW-2 β	SW-2 γ
E_b /eV	1.66	1.59	1.02	0.88	0.83	0.62	0.61	3.36	2.44	2.40
r_{HN} /Å	—	—	—	1.28	1.04	—	—	—	1.23	—
r_{HB} /Å	1.36	1.26	1.26	—	—	1.31	1.32	1.21	1.04	1.02-1.03

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